<u>onsemi.</u>

Digital Transistors (BRT) R1 = 2.2 k Ω , **R2 =** ∞ **k** Ω

MUN2238, MMUN2238L, MUN5238, DTC123TE, DTC123TM3, NSBC123TF3

NPN Transistors with Monolithic Bias Resistor Network

This series of digital transistors is designed to replace a single device and its external resistor bias network. The Bias Resistor Transistor (BRT) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a baseemitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space.

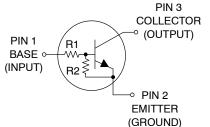
Features

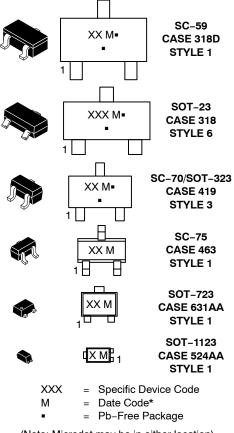
- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Rating	Symbol	Max	Unit
Collector-Base Voltage	V _{CBO}	50	Vdc
Collector-Emitter Voltage	V _{CEO}	50	Vdc
Collector Current – Continuous	۱ _C	100	mAdc
Input Forward Voltage	V _{IN(fwd)}	12	Vdc
Input Reverse Voltage	V _{IN(rev)}	6	Vdc

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

PIN CONNECTIONS





(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet. NOTE: Some of the device on this data sheet have been **DISCONTINUED**. Please refer to the table on page 2.

Table 1. ORDERING INFORMATION

Device	Part Marking	Package	Shipping [†]
MMUN2238LT1G, SMMUN2238LTIG*	A8R	SOT-23 (Pb-Free)	3000 / Tape & Reel
MUN5238T1G	AQ	SC-70/SOT-323 (Pb-Free)	3000 / Tape & Reel
DTC123TET1G	7R	SC–75 (Pb–Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <u>BRD8011/D.</u>

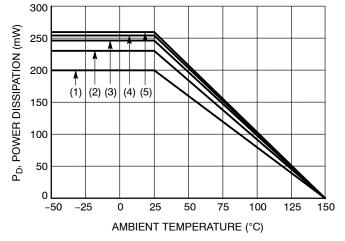
*S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

DISCONTINUED (Note 1)

Device	Part Marking	Package	Shipping [†]
MUN2238T1G	6Q	SC–59 (Pb–Free)	3000 / Tape & Reel
DTC123TM3T5G	7C	SOT-732 (Pb-Free)	8000 / Tape & Reel
NSBC123TF3T5G	Т	SOT-1123 (Pb-Free)	8000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <u>BRD8011/D.</u>

1. **DISCONTINUED:** This device is not recommended for new design. Please contact your **onsemi** representative for information. The most current information on this device may be available on <u>www.onsemi.com</u>.



SC-75 and SC-70/SOT323; Minimum Pad
SC-59; Minimum Pad
SOT-23; Minimum Pad
SOT-1123; 100 mm², 1 oz. copper trace

(4) SOT-1123; 100 mm², 1 oz. copper tra (5) SOT-723; Minimum Pad

Figure 1. Derating Curve

Table 2. THERMAL CHARACTERISTICS

Characteristic		Symbol	Max	Unit
THERMAL CHARACTERISTICS (SC-59) (MUN2238)				
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C	(Note 2) (Note 3) (Note 2)	P _D	230 338 1.8	mW mW/°C
	(Note 2) (Note 3)		2.7	11100/ 0
Thermal Resistance, Junction to Ambient	(Note 2) (Note 3)	$R_{ hetaJA}$	540 370	°C/W
Thermal Resistance, Junction to Lead	(Note 2) (Note 3)	$R_{\theta JL}$	264 287	°C/W
Junction and Storage Temperature Range		T _J , T _{stg}	–55 to +150	°C
THERMAL CHARACTERISTICS (SOT-23) (MMUN2238L)				
Total Device Dissipation $T_A = 25^{\circ}C$	(Note 2) (Note 3)	P _D	246 400	mW
Derate above 25°C	(Note 2) (Note 3)		2.0 3.2	mW/°C
Thermal Resistance, Junction to Ambient	(Note 1) (Note 3)	R_{\thetaJA}	508 311	°C/W
Thermal Resistance, Junction to Lead	(Note 2) (Note 3)	R_{\thetaJL}	174 208	°C/W
Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +150	°C
THERMAL CHARACTERISTICS (SC-70/SOT-323) (MUN5238)				
Total Device Dissipation	(Nata O)	PD	000	
T _A = 25°C Derate above 25°C	(Note 2) (Note 3) (Note 2) (Note 3)		202 310 1.6 2.5	mW mW/°C
Thermal Resistance, Junction to Ambient	(Note 2) (Note 3)	R_{\thetaJA}	618 403	°C/W
Thermal Resistance, Junction to Lead	(Note 2) (Note 3)	$R_{ hetaJL}$	280 332	°C/W
Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +150	°C
THERMAL CHARACTERISTICS (SC-75) (DTC123TE)				
Total Device Dissipation $T_A = 25^{\circ}C$	(Note 2) (Note 3)	PD	200 300	mW
Derate above 25°C	(Note 2) (Note 3)		1.6 2.4	mW/°C
Thermal Resistance, Junction to Ambient	(Note 2) (Note 3)	R_{\thetaJA}	600 400	°C/W
Junction and Storage Temperature Range		T _J , T _{stg}	–55 to +150	°C
THERMAL CHARACTERISTICS (SOT-723) (DTC123TM3)				
Total Device Dissipation $T_A = 25^{\circ}C$	(Note 2) (Note 3)	P _D	260 600	mW
Derate above 25°C	(Note 2) (Note 3)		2.0 4.8	mW/°C
Thermal Resistance, Junction to Ambient	(Note 2) (Note 3)	R_{\thetaJA}	480 205	°C/W
Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +150	°C

Table 2. THERMAL CHARACTERISTICS

Characteristic		Symbol	Max	Unit
THERMAL CHARACTERISTICS (SOT-1123) (NSBC123TF3)				
Total Device Dissipation T _A = 25°C Derate above 25°C	(Note 4) (Note 5) (Note 4) (Note 5)	P _D	254 297 2.0 2.4	mW mW/°C
Thermal Resistance, Junction to Ambient	(Note 4) (Note 5)	$R_{ hetaJA}$	493 421	°C/W
Thermal Resistance, Junction to Lead	(Note 4)	$R_{ ext{ heta}JL}$	193	°C/W
Junction and Storage Temperature Range		T _J , T _{stg}	–55 to +150	°C

FR-4 @ Minimum Pad.
FR-4 @ 1.0 x 1.0 Inch Pad.

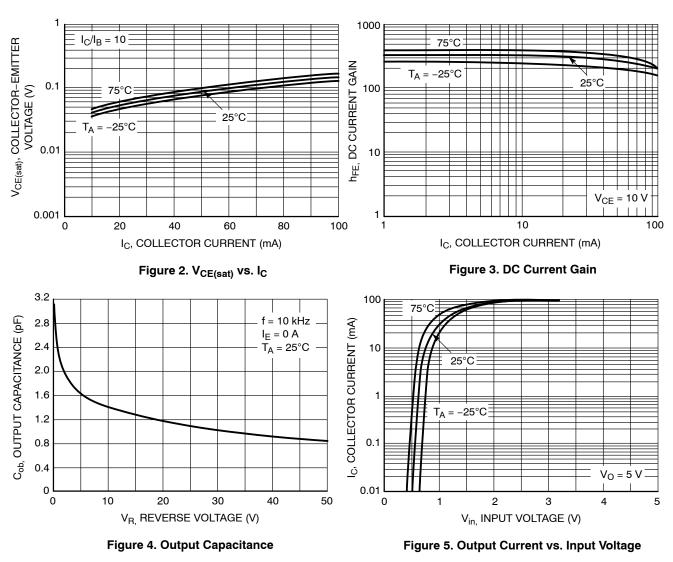
FR-4 @ 100 mm², 1 oz. copper traces, still air.
FR-4 @ 500 mm², 1 oz. copper traces, still air.

Table 3. ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$, unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector-Base Cutoff Current ($V_{CB} = 50 \text{ V}, I_E = 0$)	I _{CBO}	_	_	100	nAdc
Collector-Emitter Cutoff Current $(V_{CE} = 50 \text{ V}, I_B = 0)$	I _{CEO}	_	-	500	nAdc
Emitter-Base Cutoff Current $(V_{EB} = 6.0 \text{ V}, I_C = 0)$	I _{EBO}	_	_	4.0	mAdc
Collector–Base Breakdown Voltage $(I_C = 10 \ \mu A, I_E = 0)$	V _{(BR)CBO}	50	_	_	Vdc
Collector-Emitter Breakdown Voltage (Note 6) $(I_C = 2.0 \text{ mA}, I_B = 0)$	V _{(BR)CEO}	50	_	-	Vdc
ON CHARACTERISTICS					
DC Current Gain (Note 6) $(I_C = 5.0 \text{ mA}, V_{CE} = 10 \text{ V})$	h _{FE}	160	350	-	
Collector-Emitter Saturation Voltage (Note 6) $(I_C = 10 \text{ mA}, I_B = 1.0 \text{ mA})$	V _{CE(sat)}	-	_	0.25	Vdc
Input Voltage (off) $(V_{CE} = 5.0 \text{ V}, I_C = 100 \mu\text{A})$	V _{i(off)}	-	0.6	0.5	Vdc
Input Voltage (on) ($V_{CE} = 0.3 \text{ V}, I_C = 10 \text{ mA}$)	V _{i(on)}	1.1	0.8	-	Vdc
Output Voltage (on) (V _{CC} = 5.0 V, V _B = 2.5 V, R _L = 1.0 k Ω)	V _{OL}	-	_	0.2	Vdc
Output Voltage (off) $(V_{CC} = 5.0 \text{ V}, V_B = 0.25 \text{ V}, R_L = 1.0 \text{ k}\Omega)$	V _{OH}	4.9	_	-	Vdc
Input Resistor	R1	1.5	2.2	2.9	kΩ
Resistor Ratio	R ₁ /R ₂	-	-	-	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

6. Pulsed Condition: Pulse Width = 300 msec, Duty Cycle $\leq 2\%$.



TYPICAL CHARACTERISTICS MUN2238, MMUN2238L, MUN5238, DTC123TE, DTC123TM3

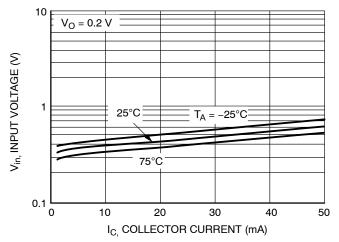
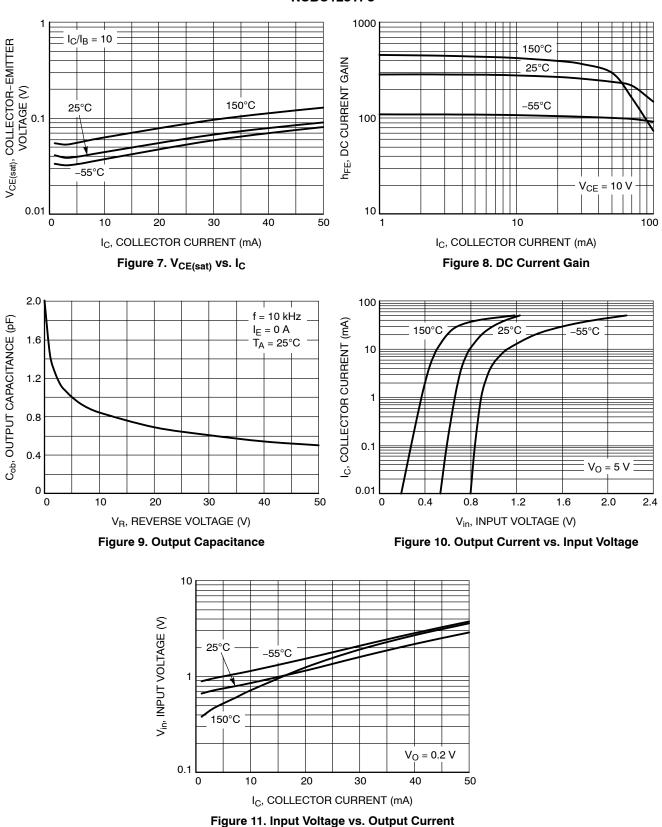


Figure 6. Input Voltage vs. Output Current



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SOT-23 (TO-236) 2.90x1.30x1.00 1.90P **CASE 318**

ISSUE AU

DATE 14 AUG 2024









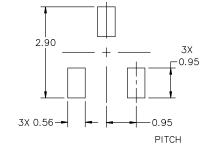




XXX = Specific Device Code М = Date Code

= Pb-Free Package .

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



MILLIMETERS					
DIM	MIN	NOM	МАХ		
А	0.89	1.00	1.11		
A1	0.01	0.06	0.10		
b	0.37	0.44	0.50		
с	0.08	0.14	0.20		
D	2.80	2.90	3.04		
E	1.20	1.30	1.40		
е	1.78	1.90	2.04		
L	0.30	0.43	0.55		
L1	0.35	0.54	0.69		
Ηe	2.10	2.40	2.64		
Т	0°		10°		

NOTES:

DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018. CONTROLLING DIMENSIONS: 1.

2. MILLIMETERS.

MILLIME IERS. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE 3.

BASE MATERIAL. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, 4. PROTRUSIONS, OR GATE BURRS.

RECOMMENDED MOUNTING FOOTPRINT

* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

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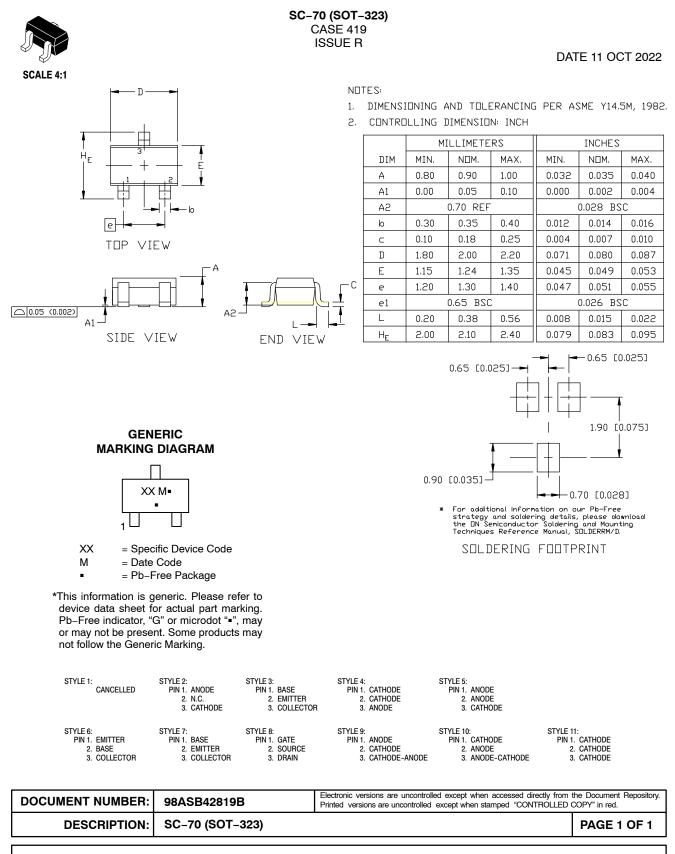
DATE 14 AUG 2024

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE	ı	
STYLE 9:	STYLE 10:	STYLE 11:	STYLE 12:	STYLE 13:	STYLE 14:
PIN 1. ANODE	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. SOURCE	PIN 1. CATHODE
2. ANODE	2. SOURCE	2. CATHODE	2. CATHODE	2. DRAIN	2. GATE
3. CATHODE	3. GATE	3. CATHODE-ANODE	3. ANODE	3. GATE	3. ANODE
STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:	STYLE 19:	STYLE 20:
PIN 1. GATE	PIN 1. ANODE	PIN 1. NO CONNECTION	PIN 1. NO CONNECTION	I PIN 1. CATHODE	PIN 1. CATHODE
2. CATHODE	2. CATHODE	2. ANODE	2. CATHODE	2. ANODE	2. ANODE
3. ANODE	3. CATHODE	3. CATHODE	3. ANODE	3. CATHODE-ANODE	3. GATE
STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
2. SOURCE	2. OUTPUT	2. ANODE	2. DRAIN	2. CATHODE	2. ANODE
3. DRAIN	3. INPUT	3. CATHODE	3. SOURCE	3. GATE	3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE				

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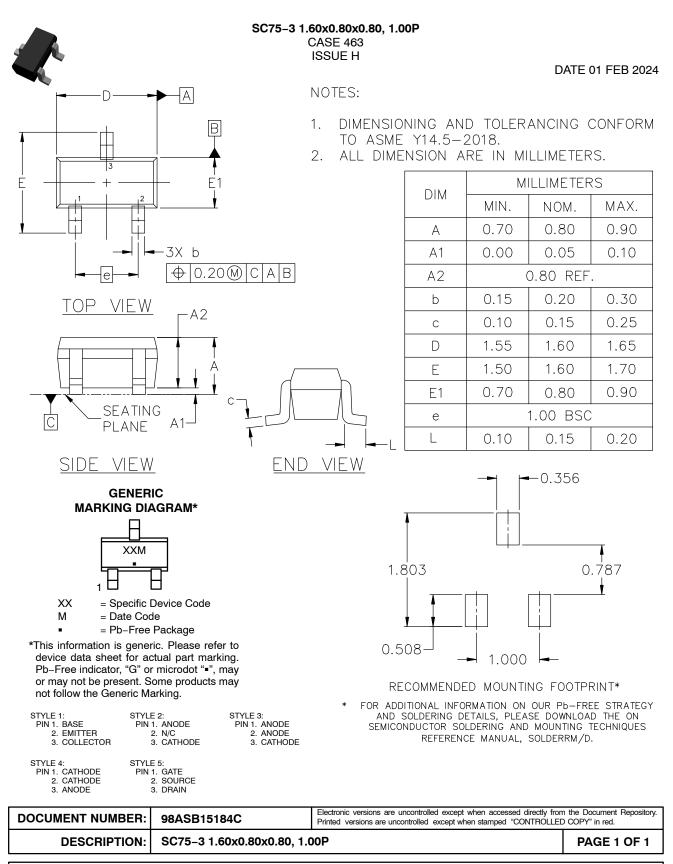
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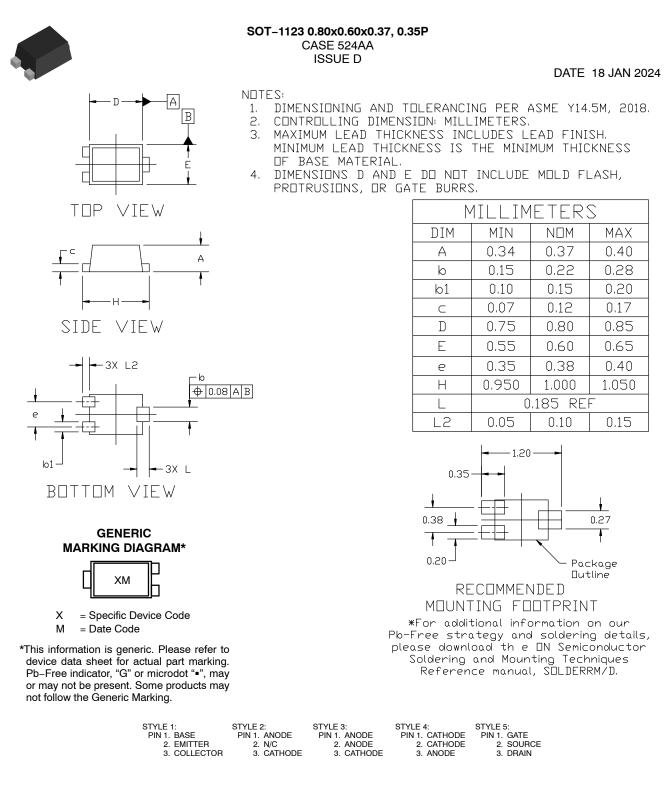
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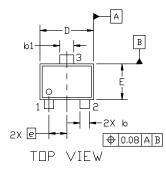


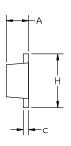
SOT-723 1.20x0.80x0.50, 0.40P CASE 631AA ISSUE E

DATE 24 JAN 2024

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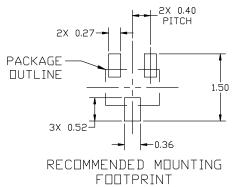
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- 2.
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- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, 4. PROTRUSIONS OR GATE BURRS.



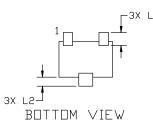


SIDE VIEW

		MILLIMETERS						
	DIM	MIN.	NDM.	MAX.				
1	А	0.45	0.50	0.55				
	b	0.15	0.21	0.27				
	b1	0.25	0.31	0.37				
	С	0.07	0.12	0.17				
	D	1.15	1.20	1.25				
	E	0.75	0.80	0.85				
	e	0.40 BSC						
	Н	1.15	1.20	1.25				
	L	0.29 REF						
	L2	0.15	0.20	0.25				



*For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.



GENERIC **MARKING DIAGRAM***



XX = Specific Device Code = Date Code Μ

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

PIN 1. BASE PIN 2. EMITTER		2. ANODE 2	4: . CATHODE . CATHODE . ANODE	STYLE 5: PIN 1. GATE 2. SOURCE 3. DRAIN		
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